

iscN-Channel MOSFET Transistor

IRFB13N50A

• FEATURES

- Low drain-source on-resistance:
 $R_{DS(ON)} = 0.45\Omega$ (MAX)
- Enhancement mode:
 $V_{th} = 2.0$ to $4.0V$ ($V_{DS} = 10 V$, $I_D=0.25mA$)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• DESCRIPTION

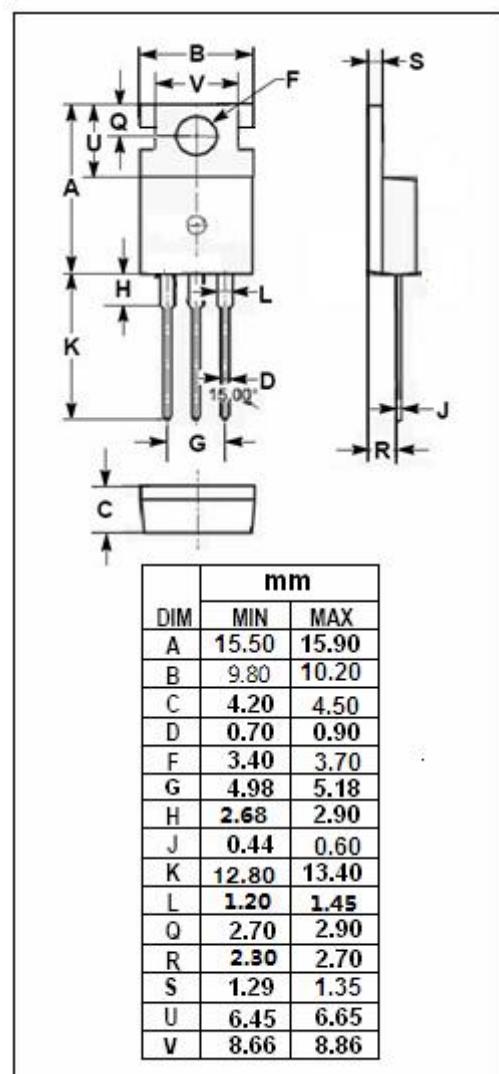
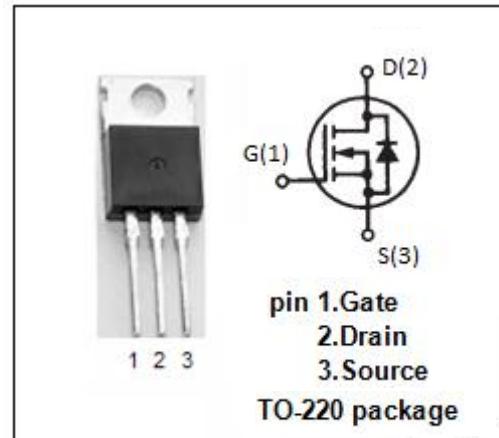
- Switching Voltage Regulators

• ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	500	V
V_{GS}	Gate-Source Voltage	± 30	V
I_D	Drain Current-Continuous	14	A
I_{DM}	Drain Current-Single Pulsed	56	A
P_D	Total Dissipation @ $T_c=25^\circ C$	250	W
T_j	Max. Operating Junction Temperature	-55~150	°C
T_{stg}	Storage Temperature	-55~150	°C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	0.5	°C/W



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ELECTRICAL CHARACTERISTICS

 $T_c=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{\text{GS}}=0\text{V}; I_{\text{D}}= 0.25\text{mA}$	500			V
$V_{\text{GS}(\text{th})}$	Gate Threshold Voltage	$V_{\text{DS}}= 10\text{V}; I_{\text{D}}=0.25\text{mA}$	2.0		4.0	V
$R_{\text{DS}(\text{on})}$	Drain-Source On-Resistance	$V_{\text{GS}}=10\text{V}; I_{\text{D}}=8.4\text{A}$			0.45	Ω
I_{GSS}	Gate-Source Leakage Current	$V_{\text{GS}}= \pm 30\text{V}; V_{\text{DS}}= 0\text{V}$			± 100	nA
I_{DSS}	Drain-Source Leakage Current	$V_{\text{DS}}=500\text{V}; V_{\text{GS}}= 0\text{V}$ $V_{\text{DS}}=400\text{V}; V_{\text{GS}}= 0\text{V}; T_J=125^\circ\text{C}$			25 250	μA
V_{SDF}	Diode forward voltage	$I_{\text{DR}} =14\text{A}, V_{\text{GS}} = 0 \text{ V}$			1.5	V

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